



SBR0220LP

0.2A SBR[®] SUPER BARRIER RECTIFIER

Features

- Low Leakage Current
- Patented Super Barrier Rectifier Technology
- Excellent High Temperature Stability
- Soft, Fast Switching Capability
- 150°C Operating Junction Temperature
- Lead Free Finish, RoHS Compliant (Note 1)
- "Green" Molding Compound (No Br, Sb)
- Qualified to AEC-Q101 Standards for High Reliability



Case: DFN1006-2

 Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0

Moisture Sensitivity: Level 1 per J-STD-020D

Polarity Indicator: Cathode Dot

 Terminals: Finish - NiPdAu over Copper leadframe. Solderable per MIL-STD-202, Method 208

Marking Information: See Page 3
 Ordering Information: See Page 3

Weight: 0.001 grams (approximate)



Top View



Bottom View

Maximum Ratings @T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	V_{RRM}		
Working Peak Reverse Voltage	V _{RWM}	20	V
DC Blocking Voltage	V_{RM}		
RMS Reverse Voltage	$V_{R(RMS)}$	14	V
Average Rectified Output Current (See Figure 1)	Io	0.2	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	5.0	А

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Maximum Thermal Resistance Thermal Resistance Junction to Soldering (Note 2) Thermal Resistance Junction to Ambient (Note 3)	$R_{ hetaJS}$ $R_{ hetaJA}$	17 304	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	۰C

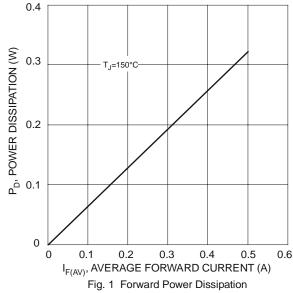
Electrical Characteristics @T_A = 25°C unless otherwise specified

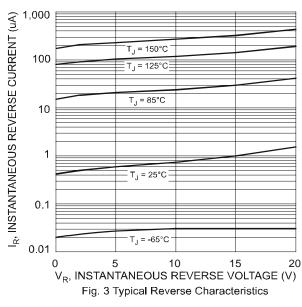
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 4)	V _{(BR)R}	20	-	=	V	I _R = 400μA
Forward Voltage Drop	V _F	-	0.38 0.30 0.44 0.38	0.42 0.33 0.48 0.41	V	I _F = 0.1A, T _J = 25°C I _F = 0.1A, T _J = 150°C I _F = 0.2A, T _J = 25°C I _F = 0.2A, T _J = 150°C
Leakage Current (Note 4)	I _R	-	2 0.43	50 1.3	•	$V_R = 20V, T_J = 25^{\circ}C$ $V_R = 20V, T_J = 150^{\circ}C$

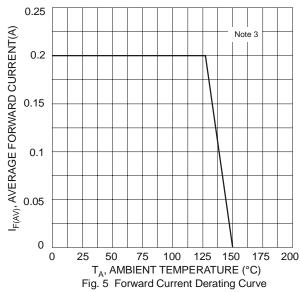
Notes:

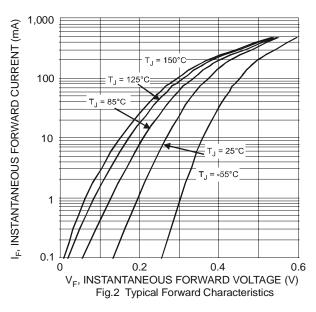
- 1. RoHS revision 13.2.2003. High temperature solder exemption applied, see *EU Directive Annex Note* 7.
- 2. Theoretical R_{0JS} calculated from the top center of the die straight down to the PCB cathode tab solder junction.
- 3. FR-4 PCB, 2oz. Copper, minimum recommended pad layout per http://www.diodes.com/datasheets/ap02001.pdf.
- 4. Short duration pulse test used to minimize self-heating effect.

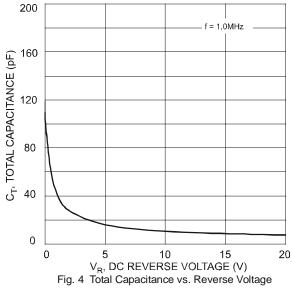


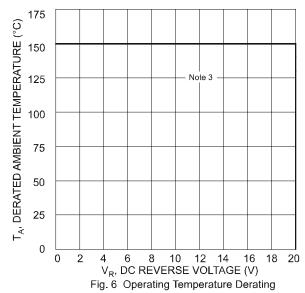












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Ordering Information (Note 5)

Part Number	Case	Packaging
SBR0220LP-7	DFN1006-2	3000/Tape & Reel

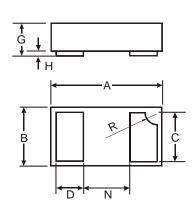
Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information

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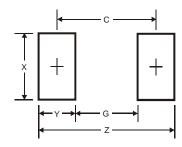
22 = Product Type Marking Code Dot Denotes Cathode Side

Package Outline Dimensions



DFN1006-2				
Dim	Min	Max	Тур	
Α	0.95	1.075	1.00	
В	0.55	0.675	0.60	
С	0.45	0.55	0.50	
D	0.20	0.30	0.25	
G	0.47	0.53	0.50	
Н	0	0.05	0.03	
N	_	_	0.40	
R	0.05	0.15	0.10	
All Dimensions in mm				

Suggested Pad Layout



Dimensions	Value (in mm)
Z	1.1
G	0.3
Х	0.7
Y	0.4
С	0.7

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